NSN 5961-01-564-9795

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-564-9795 **Inclosure Material:** Metal **Overall Length:** 19.6 millimeters **Terminal Length:** 13.2 millimeters **Overall Diameter:** 4.7 millimeters **Function For Which Designed:** Phototransistor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 70.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 100.00 nanoamperes zero-gate-voltage source current absolute **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector preset **Special Features:** Lens window; high photo sensitivity; lead (pb)-free component **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:**